Attorney Docket No.: 99CON114P

## In the Claims:

Claims 1-27 (canceled).

Claim 28 (currently amended): A method comprising steps of:

covering a first area inof a dielectric layer, said dielectric layer having a first dielectric constant;

exposing a second area in said dielectric <u>layer</u> to a dielectric conversion source so as to increase said first dielectric constant of said dielectric <u>layer</u> in said second area to a second dielectric constant;

etching a plurality of capacitor trenches in said second area in said dielectric layer;

wherein said dielectric conversion source emprises is selected from the group consisting of E-beams, I-beams, an amine based chemical, and an oxygen plasma.

Claim 29 (currently amended): A method comprising steps of:

etching a plurality of capacitor trenches in a second area in a dielectric layer, said

dielectric layer having a first dielectric constant;

covering a first area inof said a-dielectric layer, said dielectric having a first dielectric constant;

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exposing asaid second area in said dielectric layer to a dielectric conversion source so as to increase said first dielectric constant of said dielectric layer in said second area to a second dielectric constant;

wherein said dielectric conversion source emprises is selected from the group consisting of I-beams, E-beams, an amine based chemical, and an oxygen plasma.

Claim 30 (currently amended): A method comprising steps of:

covering a first area in a dielectric, said dielectric having a first dielectric constant;

exposing a second area in said dielectric to a dielectric conversion source

so as to increase said first dielectric constant of said dielectric in said second area

to a second dielectric constant, wherein said covering said first area in said

dielectric prevents said first area from being exposed to said dielectric conversion

source;

wherein said dielectric conversion source comprises an amine based chemical.

Claim 31 (currently amended): A method comprising steps of:

covering a first area in a dielectric, said dielectric having a first dielectric constant;

exposing a second area in said dielectric to a dielectric conversion source

so as to increase said first dielectric constant of said dielectric in said second area

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to a second dielectric constant, wherein said covering said first area in said

dielectric prevents said first area from being exposed to said dielectric conversion

source;

wherein said dielectric conversion source comprises oxygen plasma.